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Facsimile Cover Sheet

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To:	US Patent & Trademark Office Fax: 703-746-9195 Tel: 703-308-1202
From:	David E. Steuber Tel: 408/982-8200 ext. 1 Fax: 408/982-8210
Pages	4 (excluding cover sheet)

First Inventor:	Mohamed N. Darwish
Title:	Trench MOSFET Having Implanted Drain-Drift Region And Process For Manufacturing The Same
Serial No.:	10/650,513
Examiner:	Unknown

Enclosed for filing in the above-identified application are the following:
Transmittal Form (1 page);
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Replacement Application Data Sheet (2 pages).

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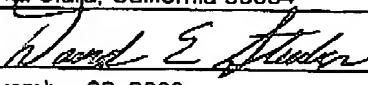
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Total Number Of Pages In This Submission	4	Attorney Docket No.	SCX010-5D US
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ENCLOSURES (check all that apply)

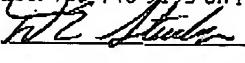
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<input type="checkbox"/> Extension of Time Request (1 page in duplicate)	<input type="checkbox"/> Power of Attorney, Revocation of Previous Powers; And Statement Under 37 CFR 3.73(b)	[REDACTED] Other Enclosure(s) (please identify below): Marked-up Copy of Filing Receipt showing correction; (1 page); and Supplemental Application Data Sheet (2 pages).
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SIGNATURE OF APPLICANT, ATTORNEY OR AGENT

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Signature	
Date	November 26, 2003

CERTIFICATE OF FACSIMILE TRANSMISSION

I hereby certify that this correspondence is being facsimile transmitted to the U.S. Patent and Trademark Office to the fax number 703-746-9795 on November 26, 2003.

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FILING RECEIPT

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Applicant(s)

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Assignment For Published Patent Application

Siliconix Incorporated, Campbell, CA;

Santa Clara

Domestic Priority data as claimed by applicant

This application is a DIV of 10/317,568 12/12/2002
 which is a CIP of 09/898,652 07/03/2001 PAT 6,569,738

Foreign Applications**If Required, Foreign Filing License Granted:** 11/19/2003**Projected Publication Date:** 02/26/2004**Non-Publication Request:** No**Early Publication Request:** No**Title**

Trench MOSFET having implanted drain-drift region and process for manufacturing the same